

Balanced ElectroAbsorption Modulated RF Photonic Link

Original

Balanced ElectroAbsorption Modulated RF Photonic Link / Cappelluti, Federica; S., Mathai; M. C., Wu; Ghione, Giovanni. - ELETTRONICO. - (2000). (Conference on Lasers and Electro-Optics Europe, 2000) [10.1109/CLEOE.2000.909918].

Availability:

This version is available at: 11583/1534158 since: 2018-04-23T09:04:46Z

Publisher:

IEEE

Published

DOI:10.1109/CLEOE.2000.909918

Terms of use:

This article is made available under terms and conditions as specified in the corresponding bibliographic description in the repository

Publisher copyright

IEEE postprint/Author's Accepted Manuscript

©2000 IEEE. Personal use of this material is permitted. Permission from IEEE must be obtained for all other uses, in any current or future media, including reprinting/republishing this material for advertising or promotional purposes, creating new collecting works, for resale or lists, or reuse of any copyrighted component of this work in other works.

(Article begins on next page)

Balanced Electroabsorption Modulated RF Photonic Link

F. Cappelluti^{1,2}, S. Mathai¹, M.C. Wu¹, G. Ghione²

¹ *Electrical Engineering Department, University of California, Los Angeles,
66-147D, Engineering IV, Box 951594, Los Angeles, California 90095-1594.
Phone Number: (310) 825-6859, Fax Number: (310) 794-5513*

² *Dipartimento di Elettronica, Politecnico di Torino, corso Duca degli Abruzzi 24, I-10129 Torino, Italy.
Phone Number: +39-0115644185, Fax Number: +39- 0115644099
E-mail: fcappell@athena.polito.it*

We propose a novel high linearity, low noise analog photonic link using a balanced electroabsorption modulator. It simultaneously cancels all common-mode intensity noises, even-order distortions and suppresses the third order intermodulation, achieving shot noise-limited performance.

Balanced Electroabsorption Modulated RF Photonic Link

F. Cappelluti^{1,2}, S. Mathai¹, M.C. Wu¹, G. Ghione²

¹ Electrical Engineering Department, University of California, Los Angeles, 66-147D, Engineering IV, Box 951594, Los Angeles, California 90095-1594. Phone Number: (310) 825-6859, Fax Number: (310) 794-5513

² Dipartimento di Elettronica, Politecnico di Torino, corso Duca degli Abruzzi 24, I-10129 Torino, Italy. Phone Number: +39- 0115644185, Fax Number: +39- 0115644099, E-mail: fcappell@athena.polito.it

Balanced RF photonic links are of great interest because they can suppress laser relative intensity noise (RIN) and amplified spontaneous emission noise (ASE) from optical amplifiers, achieving shot noise-limited performance [1]. To date, the highest performance RF photonic links have employed LiNbO₃ Mach-Zehnder modulators (X-MZM). Due to their interferometric operation, X-MZM links cannot simultaneously achieve RIN cancellation and large linear dynamic range [2].

We propose a novel balanced RF photonic link using a balanced electroabsorption modulator (B-EAM). In contrast to X-MZM, the B-EAM enables the simultaneous cancellation of laser RIN, added ASE noise, all even-order distortions, and the 3rd order distortion. The schematic of the B-EAM link is shown in fig. 1. Differential modulation of the B-EAM is achieved by feeding the RF signals to the common electrode between the two EAMs, while the DC bias is equally split between EAMs. The 180° out-of-phase signals from the two EAMs have equal amplitudes for all bias voltages. Since the balanced receiver detects the difference photocurrent, the RF signals from the two photodiodes add in phase, while common-mode noises and even-order distortion terms are cancelled.

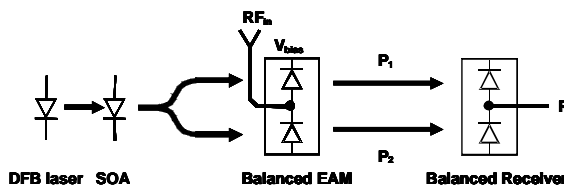


Fig. 1. Schematic of the balanced-electroabsorption-modulated link

Therefore, the bias voltage on the EAM can be used to null the 3rd order derivative of the modulator transfer function. Thus, the leading distortion term becomes the 5th order intermodulation.

We have developed a theoretical model to simulate the performance of the proposed link. The model uses a Taylor series representation of the EAM transmission function to calculate the small signal gain, harmonic and intermodulation distortions. To determine the output noise floor, thermal, shot, and intensity noises from laser and SOA have been taken into account. The equivalent $V\pi$ of the EAMs is assumed to be 0.5V. Total link loss per arm is 10 dB, amplifier gain and noise figure are 20 dB and 10 dB respectively. Biasing the EAMs at 3rd order null results in a link gain of 3.25 dB, assuming 1mW laser power. Figure 2 shows a comparison between single and balanced link in term of noise figure (NF) and spurious free dynamic range (SFDR).

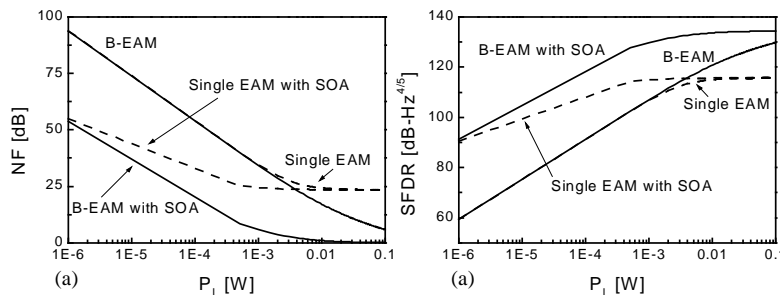


Fig. 2. (a) Calculated NF vs. P_L and (b) SFDR vs. P_L for single (dashed) and balanced (solid) EAM's.

from the SOA. In contrast, in the B-EAM link the suppression of common-mode intensity noises allows shot-noise limited performance in a much wider range of laser power. NF as low as 5.8dB and a multi-octave SFDR of 130 dB-Hz^{4/5} can be achieved with a laser power of 1 mW, in the presence of RIN as high as -140 dBc/Hz. As optical power increases, NF asymptotically approaches 0 dB and SFDR saturates since the B-EAM link is ultimately limited by the thermal noise generated at the input and successively amplified by the link.

In summary, we have proposed a novel balanced-electroabsorption-modulated link that simultaneously cancels RIN, added ASE noise, all even-order distortions, and 3rd order distortions. The B-EAM can be monolithically integrated with a DFB laser and SOA, allowing the possibility of all semiconductor RF lightwave transmitters to achieve ultra-wide spurious free dynamic range and low noise figure.

- [1] L.T. Nichols, *IEEE Microwave Theory and Techniques*, vol.45, p. 1375, 1997.
 [2] E.I. Ackerman, *MTT-Symposium*, 1993, p. 723.